

Silicon NPN Power Transistor

DESCRIPTION

- · High Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 400V(Min)
- · High Switching Speed
- · High Reliability

APPLICATIONS

- · Switching regulators
- Ultrasonic generators
- High frequency inverters
- General purpose power amplifiers

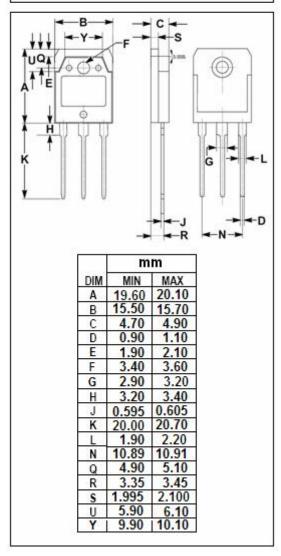
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	450	V	
V _{CEO}	Collector-Emitter Voltage	400	V	
V _{CEO(SUS)}	Collector-Emitter Voltage	400	V	
V _{EBO}	Emitter-Base voltage	7	V	
Ic	Collector Current-Continuous	10	Α	
I _B	Base Current-Continuous	3	А	
Pc	Collector Power Dissipation @ T _C =25°C	80	W	
TJ	T _J Junction Temperature		$^{\circ}$ C	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	1.17	°C/W

PIN 1. BASE 2. COLLECTOR 3. BMITTER TO-3PN package



Ordering Information

Product	Package	Packaging		
2SC2625T4TL	TO-3PN	Tube		

V01 1

1.0

 μ s



ELECTRICAL CHARACTERISTICS

T_{C} =25°C unless otherwise specified

Fall Time

 $t_{\text{f}} \\$

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA ; I _B = 0	400			V	
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 30mA ; I _B = 0	400			V	
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA ; I _E = 0	450			V	
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 0.1mA ; I _C = 0	7			V	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 4A; I _B = 0.8A			1.2	V	
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 4A; I _B = 0.8A			1.5	V	
I _{CBO}	Collector Cutoff Current	V _{CB} = 450V ; I _E =0			1.0	mA	
I _{EBO}	Emitter Cutoff Current	V _{EB} = 7V; I _C =0			0.1	mA	
h _{FE}	DC Current Gain	Ic= 4A ; Vc== 5V	10				
Switching times							
t _{on}	Turn-on Time				1.0	μs	
t _{stg}	Storage Time	lc= 7.5A , l _{B1} = -l _{B2} = 1.5A R _L = 20 Ω ;P _W =20 μ s Duty Cycle≤2%			2.0	μs	
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